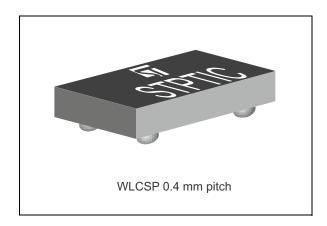




Parascan[™] tunable integrated capacitor

Datasheet - production data



Features

- High power capability
- 5:1 tuning range
- Higher linearity (48x)
- High quality factor (Q)
- Low leakage current
- Compatible with high voltage control IC (STHVDAC series)
- Available in WLCSP package 0.75 x 1.00 x 0.3
- ECOPACK[®]2 compliant component

Benefit

 RF tunable passive implementation in mobile phones to optimize antenna radiated performance

Applications

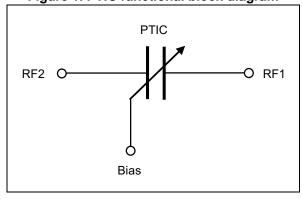
- Cellular antenna open loop tunable matching network in multi-band GSM/WCDMA/LTE mobile phone
- Open loop tunable RF filters

Description

The ST integrated tunable capacitor offers excellent RF performance, low power consumption and high linearity required in adaptive RF tuning applications. The fundamental building block of PTIC is a tunable material called Parascan™, which is a version of barium strontium titanate (BST) developed by Paratek Microwave.

BST capacitors are tunable capacitors intended for use in mobile phone application and dedicated to RF tunable applications. These tunable capacitors are controlled through an extended bias voltage ranging from 1 to 24 V. The implementation of BST tunable capacitors in mobile phones enables significant improvement in terms of radiated performance making the performance almost insensitive to the external environment.

Figure 1. PTIC functional block diagram



TM: Parascan is a trademark of Paratek Microwave Inc.

Electrical characteristics STPTIC-27L2

1 Electrical characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Rating	Unit
P _{IN}	Input peak power RF _{IN} (CW mode)/all RF ports	+40	dBm
V _{ESD(HBM)}	Human body model, JESD22-A114-B, all I/O	Class 1B ⁽¹⁾	V
V _{ESD(MM)}	Machine model, JESD22-A115-A, all I/O	100	V
T _{device}	Device temperature	+125	°C
T _{stg}	Storage temperature	-55 to +150	
V _x	Bias voltage	25	V

^{1.} Class 1B defined as passing 500 V, but fails after exposure to 1000V ESD pulse.

Table 2. Recommended operating conditions

Symbol	Devemeter	Rating	=		_		Unit
	Parameter	Min.	Min. Typ. Max.	Max.	Unit		
P _{IN}	RF input power		+33	+39	dBm		
F _{OP}	Operating frequency	700		2700	MHz		
T _{device}	Device temperature			+100	°C		
T _{OP}	Operating temperature	-30		+85			
V _{BIAS}	Bias voltage	1		24	V		

Table 3. Representative performance ($T_{amb} = 25$ °C otherwise specified)

0	B	Value Parameter Conditions				Unit
Symbol	Parameter		Min.	Тур.	Max.	Jill
C _{1V}	capacitance at 1 V bias	STPTIC-27L2	2.8	3.2	3.58	pF
C _{2V}	capacitance at 2 V bias	STPTIC-27L2	2.43	2.7	2.97	pF
C _{20V}	capacitance at 20V bias	STPTIC-27L2	0.63	0.69	0.75	pF
C _{24V}	capacitance at 24 V bias	STPTIC-27L2	0.56	0.61	0.66	pF
ΔC	Tuning range	Ratio between C _{1V} /C _{24V} ⁽¹⁾	5/1			
IL	Leakage current	Measured with V _{bias} = 24 V			100	nA
Q _{LB}	Quality factor	Measured at 700 MHz at 2 V	50	55		
Q _{HB}	Quality factor	Measured at 2700 MHz at 2 V	35	40		
		$V_{bias} = 1 V^{(2)(4)}$	60			
IP3	Third order intercept point	$V_{\text{bias}} = 24 \ V^{(2)(4)}$	80			dBm
		V _{bias} = 20 V ⁽²⁾⁽⁴⁾	80		3.58 2.97 0.75 0.66 100 -65 -75 -65 -45 -70	
		$V_{bias} = 1 V^{(3)(4)}$		-70	-65	
H2	Second harmonic	$V_{\text{bias}} = 24 \ V^{(3)(4)}$		-80	-75	dBm
		$V_{\text{bias}} = 20 \ V^{(3)(4)}$			-65	
		$V_{\text{bias}} = 1 \ V^{(3)(4)}$		-55	-45	
НЗ	Third harmonic	$V_{\text{bias}} = 24 \ V^{(3)(4)}$		-85	-70	dBm
		V _{bias} = 20 V ⁽³⁾⁽⁴⁾			-70	
4	Transition time	Average for any transition between C _{min} to C _{max} ⁽⁵⁾		50		
t _T	Transition time	Average transition between C _{max} to C _{min} ⁽⁵⁾		30		μs

^{1.} Measured at low frequency

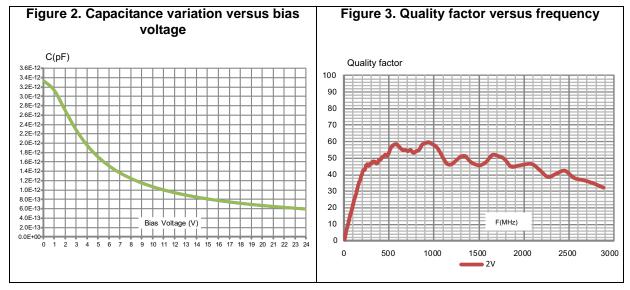
^{2.} $F_1 = 894$ MHz, $F_2 = 849$ MHz, $P_1 = +25$ dBm, $P_2 = +25$ dBm, $2f_1 - f_2 = 939$ MHz

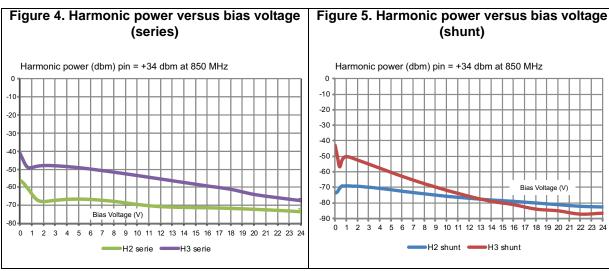
^{3. 850} MHz, $P_{in} = +34 \text{ dBm}$, CW

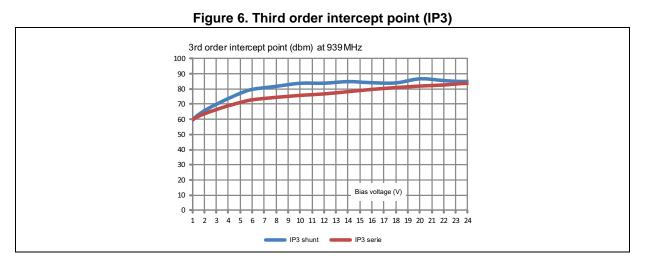
^{4.} IP3 and harmonics are measured in the shunt configuration in a 50 Ω environment

^{5.} One or both of RF_{in} and RF_{out} must be connected to DC ground, using the HVDAC turbo mode

Electrical characteristics STPTIC-27L2







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STPTIC-27L2 Package information

2 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 Flip-Chip package information

Bottom view Top view Side view (balls down) (balls up) C2 A2 D3 D2 В1 BIAS E1 B2 Α1 RF2 E2 В4 C2 ▶|C1 ▶C1

Figure 7. Flip-Chip package outline

The land pattern below is recommended for soldering the STPTIC-G2 on PCB.

NC stands for No Connect, this pad must not be connected on application board. Please leave this pad floating.

Dimensions (in microns) Α1 **A2** В1 **B2 B4** C1 C2 D1 D2 D3 **E**1 **E2** STPTIC-27L2 1000 750 140 500 360 105 540 225 90 315 125 165 ±15 Tolerance ±30 ±30 ±10 ±15 ±15 ±10 ±20 ±20 ±40 ±20 ±20

Table 4. Flip-Chip package dimensions

Package information STPTIC-27L2

Figure 8. Recommended PCB land pattern for Flip-Chip package

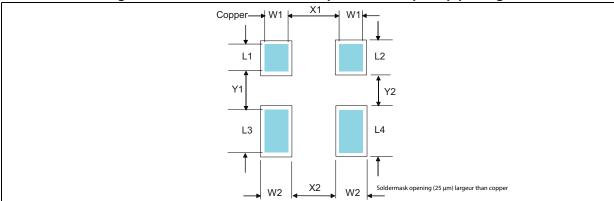


Table 5. Dimensions

Dimensions	L1	W1	L3	L2	W2	L4	X1	X2	Y1	Y2
Typical values (in microns)	160	160	260	210	210	310	320	270	240	190

Packing information 2.2

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Figure 9. Flip-Chip tape and reel outline

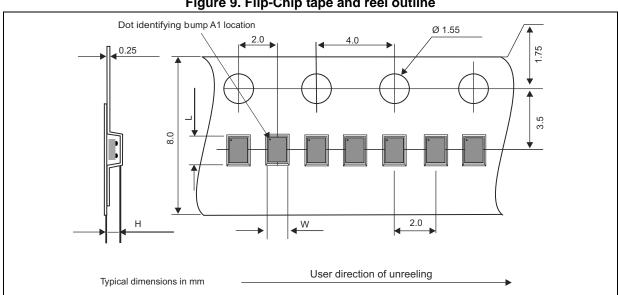


Table 6. Dimensions

Pocket dimensions	L	W	Н
STPTIC-27L2	1070	820	380

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Figure 10. Flip-Chip marking

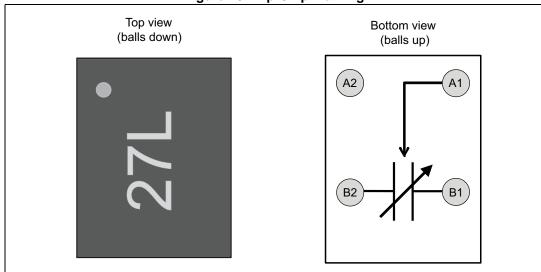


Table 7. Pinout description

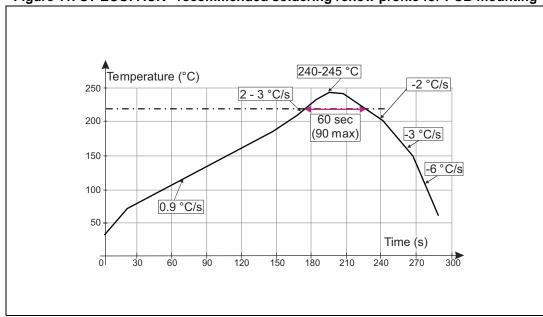
Pad / ball number	Pin name	Description
A1	DC bias	DC bias voltage
B1	RF2	RF input / output ⁽¹⁾
A2	NC	Not connected
B2	RF1	RF input / output

^{1.} When connected in shunt, please connect RF2 (B1 ball) to GND

Reflow profile STPTIC-27L2

3 Reflow profile

Figure 11. ST ECOPACK® recommended soldering reflow profile for PCB mounting



Note: Minimize air convection currents in the reflow oven to avoid component movement.

Table 8. Recommended values for soldering reflow

Profile	Va	lue	
Profile	Typical	Max.	
Temperature gradient in preheat (T = 70-180 °C)	0.9 °C/s	3 °C/s	
Temperature gradient (T = 200-225 °C)	2 °C/s	3 °C/s	
Peak temperature in reflow	240-245 °C	260 °C	
Time above 220 °C	60 s	90 s	
Temperature gradient in cooling	-2 to -3 °C/s	-6 °C/s	
Time from 50 to 220 °C	160 to 220 s		

4 Ordering information

Figure 12. Ordering information scheme

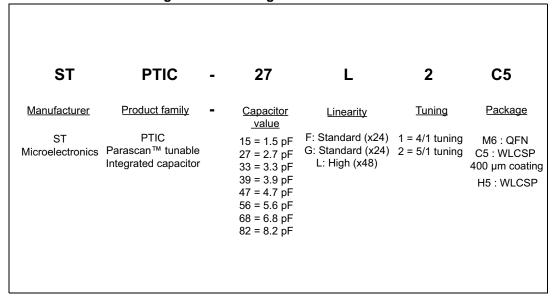


Table 9. Ordering information

Part number	Marking	Base qty	Package	Delivery mode
STPTIC-27L2C5	27L	15 000	Flip-Chip	Tape and reel

5 Revision history

Table 10. Document revision history

Date	Revision	Changes
04-Dec-2015	1	Initial release.

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